

AZ10EL16VO

AZ100EL16VO

ECL/PECL Oscillator Gain Stage and Buffer with Enable

FEATURES

- Green and RoHS Compliant Available
- 250ps Propagation Delay on Q Output
- High Voltage Gain vs. Standard EL16
- -147 dBc/Hz Typical Noise Floor in Oscillator Applications
- Available in 2x2 or 3x3mm MLP Package
- 75k Ω Enable Pull-Down Resistor
- S-Parameter (.s2p) and IBIS Model Files Available on Arizona Microtek Website
- >2 kV HBM ESD Protection
- Additional ESD Data Available on Arizona Microtek Website

PACKAGE AVAILABILITY

PACKAGE	PART NUMBER	MARKING	NOTES
MLP 8 (2x2) Green / RoHS Compliant / Lead (Pb) Free	AZ100EL16VONG	P0G <Date Code>	1,2
MLP 8 (2x2x0.75) Green / RoHS Compliant / Lead (Pb) Free	AZ100EL16VONBG	P4G <Date Code>	1,2
MLP 16 (3x3) Green / RoHS Compliant / Lead (Pb) Free	AZ10/100EL16VOLG	AZMG 16J <Date Code>	1,2
MSOP 8 RoHS Compliant / Lead (Pb) Free	AZ100EL16VOT+	HVO+ <Date Code>	1,2,4
MSOP 10 RoHS Compliant / Lead (Pb) Free	AZ100EL16VOU+	AZH+ 16VOU	1,2,3

- 1 Add R1 at end of part number for 7 inch (1K parts), R2 for 13 inch (2.5K parts) Tape & Reel.
- 2 Date code format: "Y" or "YY" for year followed by "WW" for week.
- 3 Date code "YWW" on underside of part.
- 4 Date code "YWW" on underside of part for code 141 or earlier.
The top is marked "AZH+
16VO"

DESCRIPTION

The AZ10/100EL16VO is an oscillator gain stage with a high gain output buffer including an enable. The Q_{HG}/Q_{HG} outputs have a voltage gain several times greater than the Q/Q outputs. An enable input (EN) allows continuous oscillator operation. When EN is LOW or floating (NC), input data is passed to both sets of outputs. When EN is HIGH, the Q_{HG}/Q_{HG} outputs will be forced LOW/HIGH respectively, while input data will continue to be passed to the Q/Q outputs. The EN input can be driven with an ECL/PECL signal or a CMOS logic signal.

The input impedance of the D/D inputs remain constant for all operating modes since forcing the outputs via the EN pin does not power-down the chip but only disables the high gain Q_{HG}/Q_{HG} outputs.

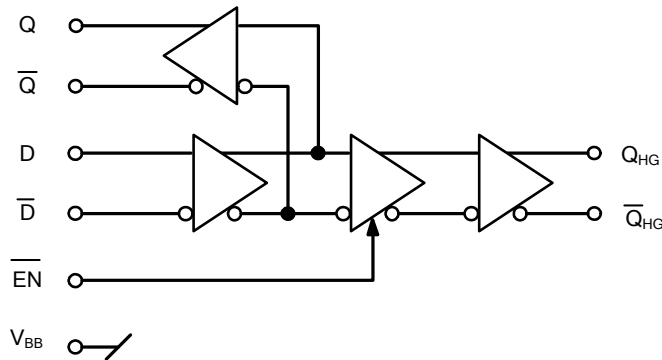
Input protection diodes are included on the D/D inputs for enhanced ESD protection.

The EL16VO also provides a V_{BB} output that supports 1.5mA sink/source current. When used, the V_{BB} pin should be bypassed to ground or V_{CC} via a 0.01 μ F capacitor.

Any used output must have an external pull down resistor. For 3.3V operation, an 180 Ω resistor to V_{EE} is recommended if an AC coupled load is present. At 5.0V, a 330 Ω resistor is recommended for the AC load case. Alternately, a 50 Ω load terminated to $V_{CC} - 2V$ or the Thevenin equivalent may be driven directly. Unused outputs may be left floating (NC).

NOTE: Specifications in ECL/PECL tables are valid when thermal equilibrium is established.

AZ10EL16VO
AZ100EL16VO



PIN DESCRIPTION

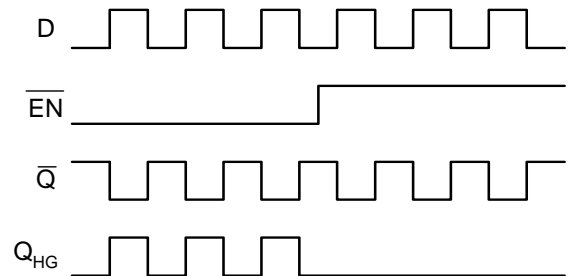
PIN	FUNCTION
D/ \bar{D}	Data Inputs
Q/ \bar{Q}	Data Outputs
Q_{HG}/\bar{Q}_{HG}	Data Outputs w/High Gain
V_{BB}	Reference Voltage Output
EN	Enable Input
V_{CC}	Positive Supply
V_{EE}	Negative Supply

TRUTH TABLE

EN	Q/Q	Q_{HG}	\bar{Q}_{HG}
LOW or NC	Data	Data	Data
HIGH	Data	LOW	HIGH

NC = No Connect

TIMING DIAGRAM



Absolute Maximum Ratings are those values beyond which device life may be impaired.

Symbol	Characteristic	Rating	Unit
V_{CC}	PECL Power Supply ($V_{EE} = 0V$)	0 to +6.0	Vdc
V_I	PECL Input Voltage ($V_{EE} = 0V$)	0 to +6.0	Vdc
V_{EE}	ECL Power Supply ($V_{CC} = 0V$)	-6.0 to 0	Vdc
V_I	ECL Input Voltage ($V_{CC} = 0V$)	-6.0 to 0	Vdc
V_{L_DIFF}	Differential Input Voltage D/ \bar{D}	0 to ± 1.6	Vpp ¹
I_{OUT}	Output Current — Continuous — Surge	50 100	mA
T_A	Operating Temperature Range	-40 to +85	°C
T_{STG}	Storage Temperature Range	-65 to +150	°C

1. V_{L_DIFF} is the voltage difference between D and \bar{D}

AZ10EL16VO
AZ100EL16VO

10K ECL DC Characteristics ($V_{EE} = -3.0V$ to $-5.5V$, $V_{CC} = GND$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output HIGH Voltage ¹	-1080		-890	-1020		-840	-980		-810	-910		-720	mV
V_{OL}	Output LOW Voltage ¹	-1950		-1650	-1950		-1630	-1950		-1630	-1950		-1595	mV
V_{IH}	Input HIGH Voltage	D/D		-430	-1170		-380	-1130		-360	-1060		-310	mV
		EN	-1230	V_{CC}	-1170	V_{CC}	-1130	V_{CC}	-1060	V_{CC}	-1060	V_{CC}	-310	V_{CC}
V_{IL}	Input LOW Voltage	D/D		-1500	-2260		-1480	-2240		-1480	-2190		-1445	mV
		EN	-2300	V_{EE}	-1500	V_{EE}	-1480	V_{EE}	-1480	V_{EE}	-1480	V_{EE}	-1445	V_{EE}
V_{BB}	Reference Voltage	-1430		-1300	-1380		-1260	-1360		-1240	-1310		-1190	mV
I_{IH}	Input HIGH Current	D/D		60			60			60			60	μA
		EN		150			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5				0.5			0.5	μA	
I_{EE}	Power Supply Current			40			40			40			40	mA

1. Each output is terminated through a 50 Ω resistor to $V_{CC} - 2V$.

10K LVPECL DC Characteristics ($V_{EE} = GND$, $V_{CC} = +3.3V$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
V_{OH}	Output HIGH Voltage ^{1,2}	2220		2410	2280		2460	2320		2490	2390		2580	mV
V_{OL}	Output LOW Voltage ^{1,2}	1350		1650	1350		1670	1350		1670	1350		1705	mV
V_{IH}	Input HIGH Voltage	D/D ¹		2870	2130		2920	2170		2940	2240		2990	mV
		EN	2070	V_{CC}	2130 ¹	V_{CC}	2170 ¹	V_{CC}	2240 ¹	V_{CC}	2240 ¹	V_{CC}	2990	V_{CC}
V_{IL}	Input LOW Voltage	D/D ¹		1800	1040		1820	1060		1820	1110		1855	mV
		EN	1000	V_{EE}	1800 ¹	V_{EE}	1820 ¹	V_{EE}	1820 ¹	V_{EE}	1820 ¹	V_{EE}	1855	1855 ¹
V_{BB}	Reference Voltage ¹	1870		2000	1920		2040	1940		2060	1990		2110	mV
I_{IH}	Input HIGH Current	D/D		60			60			60			60	μA
		EN		150			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5				0.5			0.5	μA	
EN ³		-300			-300				-300			-300	μA	
I_{EE}	Power Supply Current			40			40			40			40	mA

- For supply voltages other than 3.3V, use the ECL table values and ADD supply voltage value.
- Each output is terminated through a 50 Ω resistor to $V_{CC} - 2V$.
- Specified with EN forced to V_{EE} .

AZ10EL16VO
AZ100EL16VO

10K PECL DC Characteristics ($V_{EE} = \text{GND}$, $V_{CC} = +5.0\text{V}$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
V_{OH}	Output HIGH Voltage ^{1,2}	3920		4110	3980		4160	4020		4190	4090		4280	mV	
V_{OL}	Output LOW Voltage ^{1,2}	3050		3350	3050		3370	3050		3370	3050		3405	mV	
V_{IH}	Input HIGH Voltage	D/D ¹	3770		4570	3830		4620	3870		4640	3940		4690	mV
		EN	3770 ¹		V_{CC}	3830 ¹		V_{CC}	3870 ¹		V_{CC}	3940 ¹		V_{CC}	
V_{IL}	Input LOW Voltage	D/D ¹	2700		3500	2740		3520	2760		3520	2810		3555	mV
		EN	V_{EE}		3500 ¹	V_{EE}		3520 ¹	V_{EE}		3520 ¹	V_{EE}		3555 ¹	
V_{BB}	Reference Voltage ¹	3570		3700	3620		3740	3640		3760	3690		3810	mV	
I_{IH}	Input HIGH Current	D/D			60			60			60			60	μA
		EN			150			150			150			150	
I_{IL}	Input LOW Current	D/D	0.5		0.5		0.5		0.5		0.5		0.5	μA	
		EN ³	-1400		-1400		-1400		-1400		-1400		-1400		
I_{EE}	Power Supply Current			40			40			40			40	mA	

1. For supply voltages other than 5.0V, use the ECL table values and ADD supply voltage value.
2. Each output is terminated through a 50 Ω resistor to $V_{CC} - 2\text{V}$.
3. Specified with EN forced to V_{EE} .

100K ECL DC Characteristics ($V_{EE} = -3.0\text{V}$ to -5.5V , $V_{CC} = \text{GND}$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
V_{OH}	Output HIGH Voltage ¹	-1085		-880	-1025		-880	-1025		-880	-1025		-880	mV	
V_{OL}	Output LOW Voltage ¹	-1900		-1555	-1900		-1620	-1900		-1620	-1900		-1620	mV	
V_{IH}	Input HIGH Voltage	D/D	-1165		-390	-1165		-390	-1165		-390	-1165		-390	mV
		EN	-1165		V_{CC}	-1165		V_{CC}	-1165		V_{CC}	-1165		V_{CC}	
V_{IL}	Input LOW Voltage	D/D	-2250		-1475	-2250		-1475	-2250		-1475	-2250		-1475	mV
		EN	V_{EE}		-1475	V_{EE}		-1475	V_{EE}		-1475	V_{EE}		-1475	
V_{BB}	Reference Voltage	-1390		-1250	-1390		-1250	-1390		-1250	-1390		-1250	mV	
I_{IH}	Input HIGH Current	D/D			60			60			60			60	μA
		EN			150			150			150			150	
I_{IL}	Input LOW Current	0.5			0.5			0.5			0.5			μA	
I_{EE}	Power Supply Current			40			40			40			46	mA	

1. Each output is terminated through a 50 Ω resistor to $V_{CC} - 2\text{V}$.

AZ10EL16VO
AZ100EL16VO

100K LVPECL DC Characteristics ($V_{EE} = \text{GND}$, $V_{CC} = +3.3\text{V}$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
V_{OH}	Output HIGH Voltage ^{1,2}	2215		2420	2275		2420	2275		2420	2275		2420	mV	
V_{OL}	Output LOW Voltage ^{1,2}	1400		1745	1400		1680	1400		1680	1400		1680	mV	
V_{IH}	Input HIGH Voltage	D/D ¹	2135		2910	2135		2910	2135		2910	2135		2910	mV
		EN	2135 ¹		V_{CC}	2135 ¹		V_{CC}	2135 ¹		V_{CC}	2135 ¹		V_{CC}	
V_{IL}	Input LOW Voltage	D/D ¹	1050		1825	1050		1825	1050		1825	1050		1825	mV
		EN	V_{EE}		1825 ¹	V_{EE}		1825 ¹	V_{EE}		1825 ¹	V_{EE}		1825 ¹	
V_{BB}	Reference Voltage ¹	1910		2050	1910		2050	1910		2050	1910		2050	mV	
I_{IH}	Input HIGH Current	D/D			60			60			60			60	μA
		EN			150			150			150			150	
I_{IL}	Input LOW Current	D/D	0.5		0.5		0.5		0.5		0.5		0.5	μA	
		EN ³	-300		-300		-300		-300		-300		-300		
I_{EE}	Power Supply Current			40			40			40			46	mA	

1. For supply voltages other than 3.3V, use the ECL table values and ADD supply voltage value.
2. Each output is terminated through a 50Ω resistor to $V_{CC} - 2\text{V}$.
3. Specified with EN forced to V_{EE} .

100K PECL DC Characteristics ($V_{EE} = \text{GND}$, $V_{CC} = +5.0\text{V}$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit	
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max		
V_{OH}	Output HIGH Voltage ^{1,2}	3915		4120	3975		4120	3975		4120	3975		4120	mV	
V_{OL}	Output LOW Voltage ^{1,2}	3100		3445	3100		3380	3100		3380	3100		3380	mV	
V_{IH}	Input HIGH Voltage	D/D ¹	3835		4610	3835		4610	3835		4610	3835		4610	mV
		EN	3835 ¹		V_{CC}	3835 ¹		V_{CC}	3835 ¹		V_{CC}	3835 ¹		V_{CC}	
V_{IL}	Input LOW Voltage	D/D ¹	2750		3525	2750		3525	2750		3525	2750		3525	mV
		EN	V_{EE}		3525 ¹	V_{EE}		3525 ¹	V_{EE}		3525 ¹	V_{EE}		3525 ¹	
V_{BB}	Reference Voltage ¹	3610		3750	3610		3750	3610		3750	3610		3750	mV	
I_{IH}	Input HIGH Current	D/D			60			60			60			60	μA
		EN			150			150			150			150	
I_{IL}	Input LOW Current	D/D	0.5		0.5		0.5		0.5		0.5		0.5	μA	
		EN ³	-1400		-1400		-1400		-1400		-1400		-1400		
I_{EE}	Power Supply Current			40			40			40			46	mA	

1. For supply voltages other than 5.0V, use the ECL table values and ADD supply voltage value.
2. Each output is terminated through a 50Ω resistor to $V_{CC} - 2\text{V}$.
3. Specified with EN forced to V_{EE} .

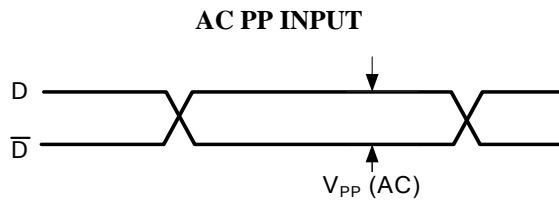
AZ10EL16VO

AZ100EL16VO

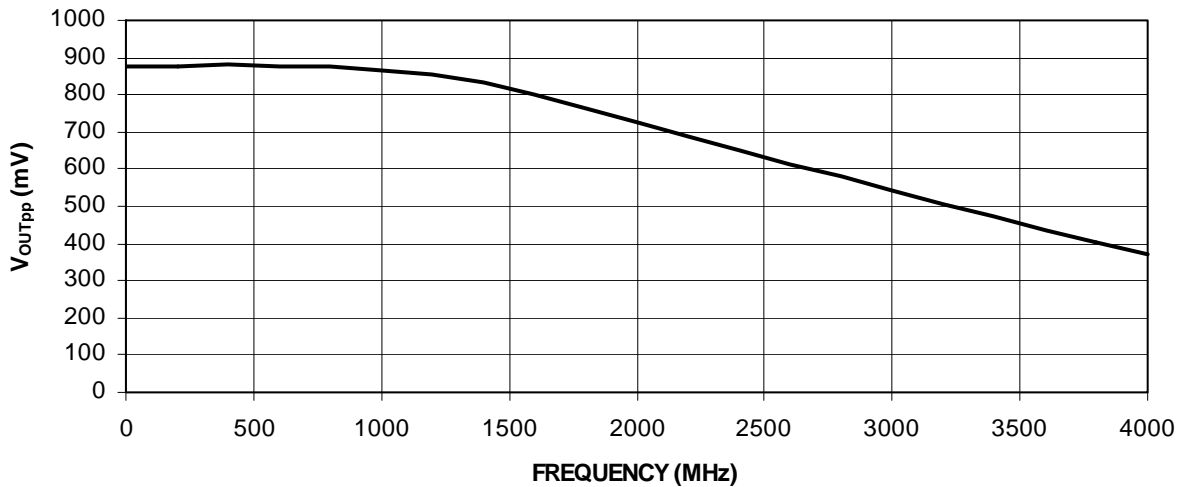
AC Characteristics ($V_{EE} = -3.0V$ to $-5.5V$; $V_{CC} = GND$ or $V_{EE} = GND$, $V_{CC} = +3.0V$ to $+5.5V$)

Symbol	Characteristic	-40°C			0°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
t_{PLH}/t_{PHL}	Propagation Delay D to Q/Q Outputs (SE)	100		300	100		300	100	200	300	100		300	ps
	D to Q_{HG}/\bar{Q}_{HG} Outputs (SE)	150		450	150		450	150	290	450	150		450	
t_{SKEW}	Duty Cycle Skew ¹ (SE)		5	20		5	20		5	20		5	20	ps
$V_{PP} (AC)$	Input Swing ²	80		1000	80		1000	80		1000	80		1000	mV
t_r/t_f	Output Rise/Fall Times (20% – 80%)	80		240	80		240	80	135	240	80		240	ps

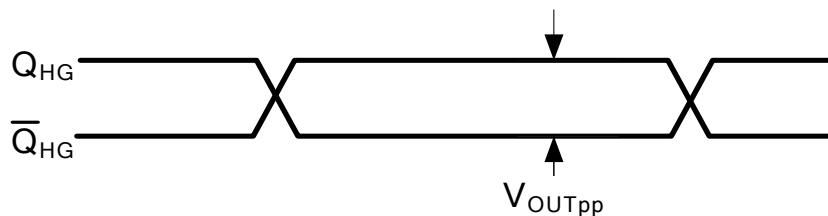
- Duty cycle skew is the difference between a t_{PLH} and t_{PHL} propagation delay through a device.
- V_{PP} is the peak-to-peak differential input swing for which AC parameters are guaranteed. The device has a voltage gain of ≈ 20 to Q/Q outputs and a voltage gain of ≈ 100 to Q_{HG}/\bar{Q}_{HG} outputs.



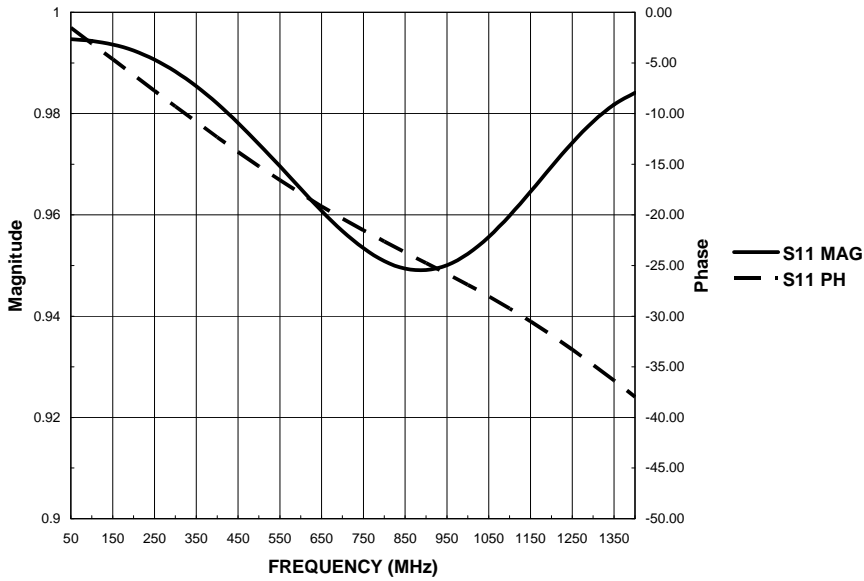
Typical Large Signal Outputs, Q_{HG}/\bar{Q}_{HG}



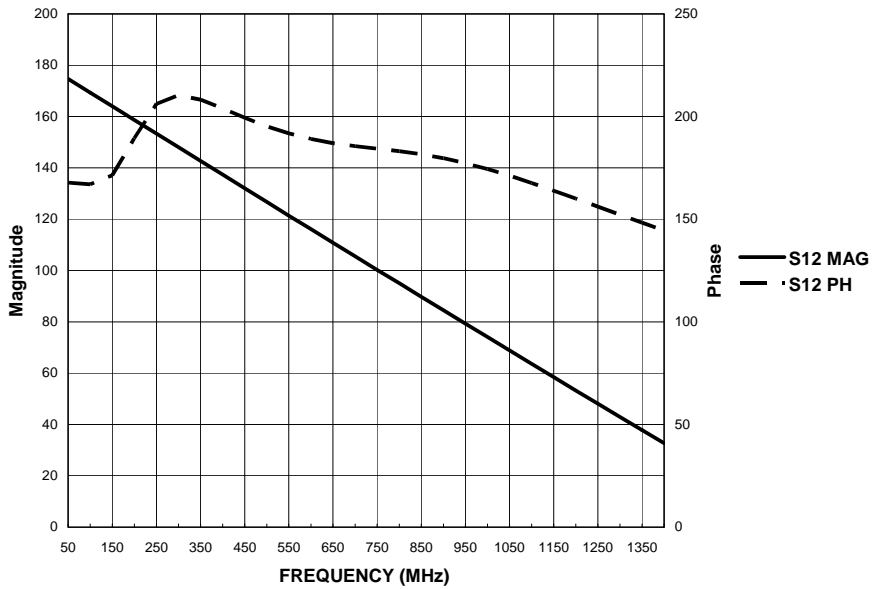
Measured with 750mv differential input, V_{EEP} NC, Q_{HG}/\bar{Q}_{HG} each terminated to $V_{CC}-2V$ via 50 Ω resistors.



AZ10EL16VO
AZ100EL16VO

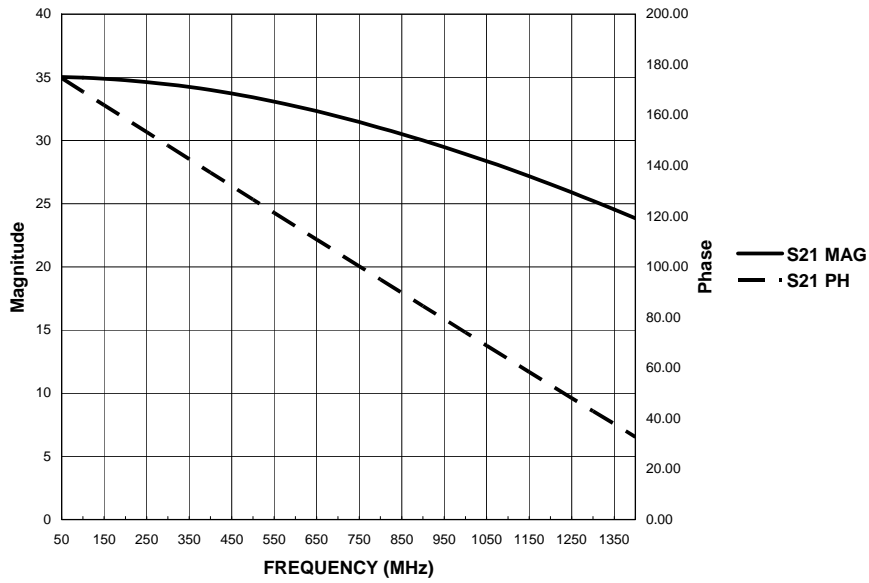


S11, D to Q, 50 Ω load to $V_{CC} - 2V$

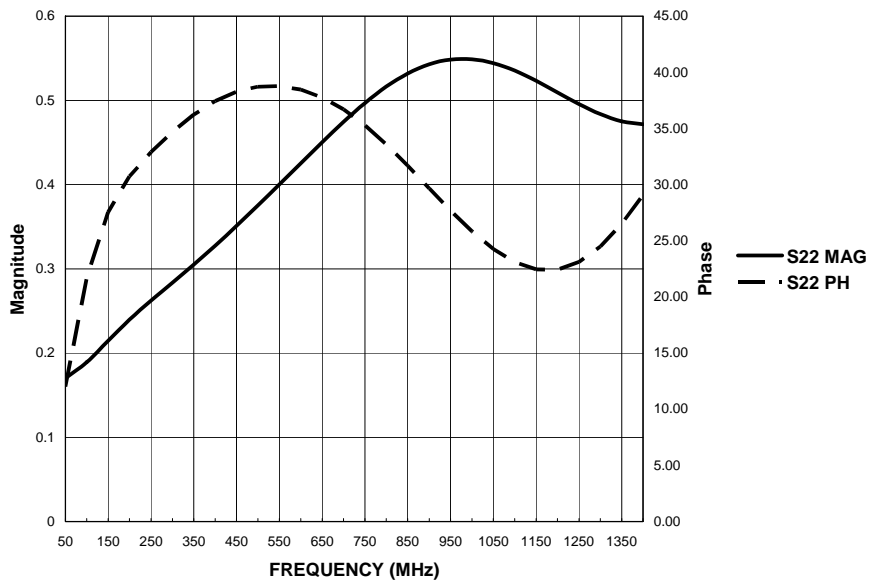


S12, D to Q, 50 Ω load to $V_{CC} - 2V$

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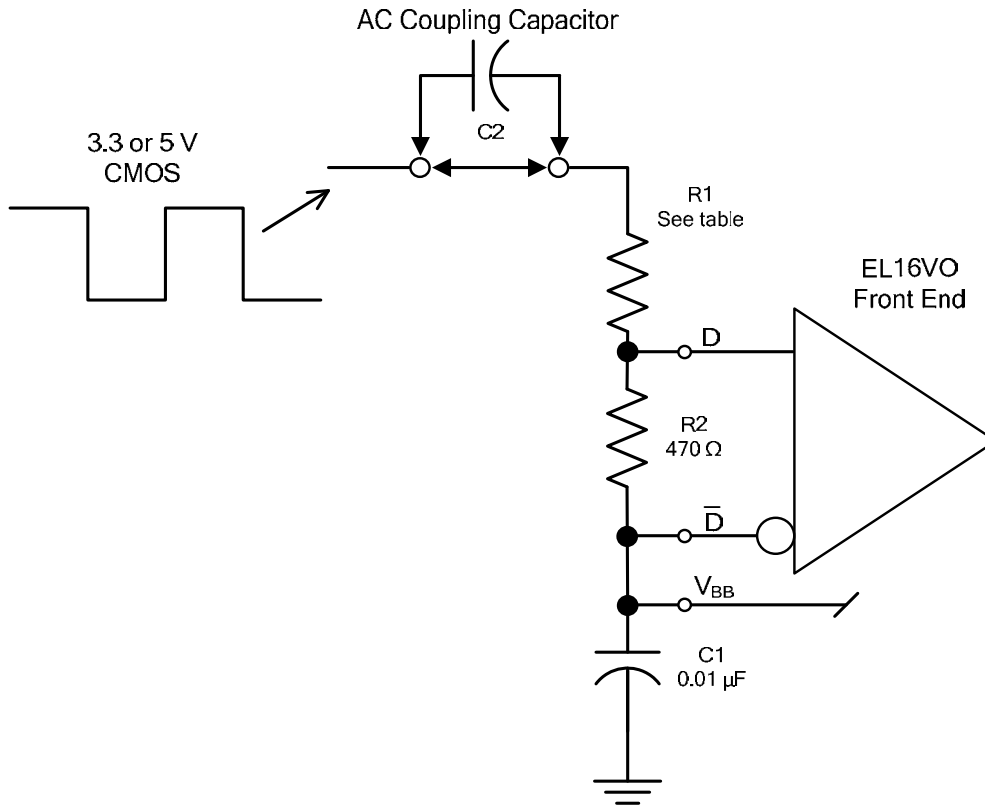


S21, D to Q, 50 Ω load to $V_{CC} - 2V$



S22, D to Q, 50 Ω load to $V_{CC} - 2V$

AZ10EL16VO
AZ100EL16VO



Application Circuit for CMOS Inputs

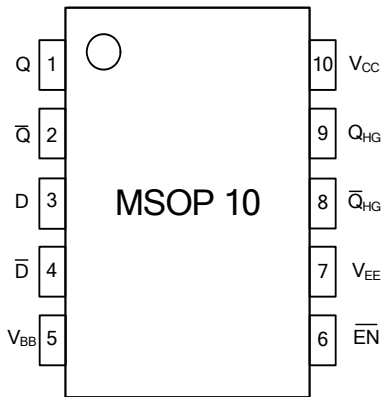
Input Type	R1 ¹	
	AC Coupled (C2 in circuit)	DC Coupled (C2 shorted)
3.3 V CMOS	430 Ω	750 Ω
5 V CMOS	910 Ω	1.8K Ω

¹ R1 should be chosen so that the input swing on the D input with respect to D is in the range of ±80 to ±1000 mV, per the AC Characteristics table.

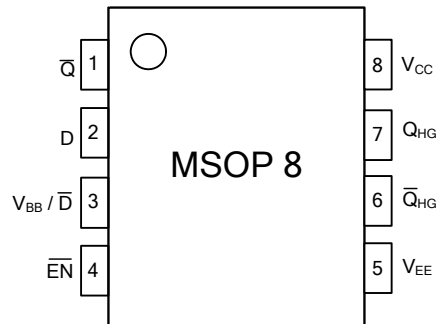
Recommended Component Values for CMOS Single Ended Inputs

AZ10EL16VO
AZ100EL16VO

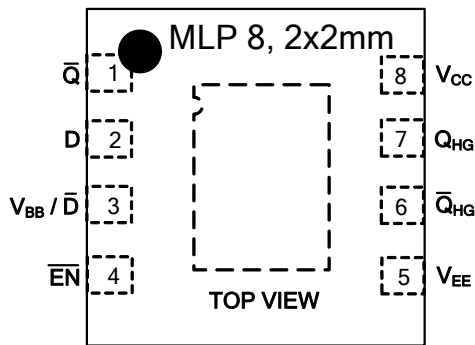
AZ100EL16VOU



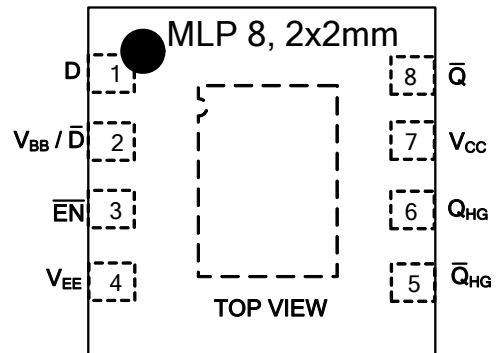
AZ100EL16VOT



AZ100EL16VON

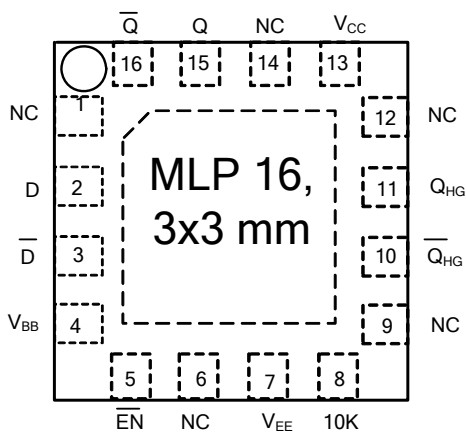


AZ100EL16VONB



MLP 8: Bottom Center Pad may be left open or tied to V_{EE}. Pin 4 is the V_{EE} return.

AZ10/100EL16VOL



MLP 16 (L) Package:
10K/100K Selection

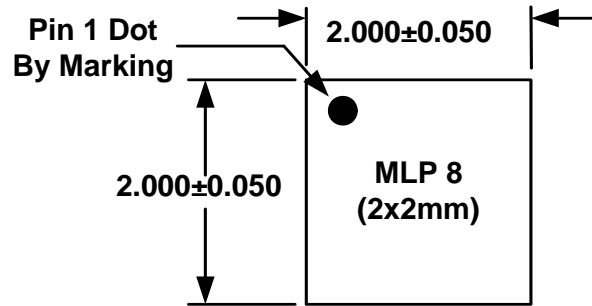
Connect 10K pin to V_{EE} to select 10K operation. Float (NC) 10K pin to select 100K operation. V_{EE} connection must be less than 1Ω.

Pin 6 of the MLP 16 package may be connected to pin 7 (V_{EE}) with no effect on the circuit.

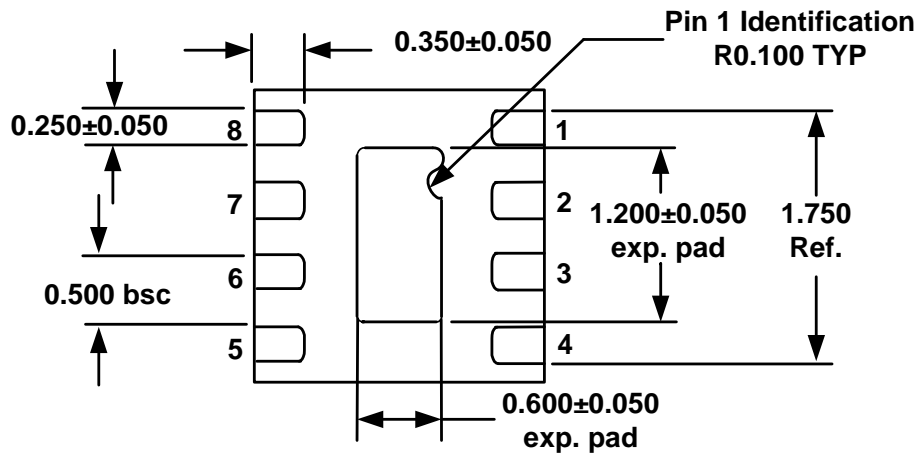
MPL 16: Bottom Center Pad may be left open or tied to V_{EE}. Pin 7 is the V_{EE} return.

AZ10EL16VO
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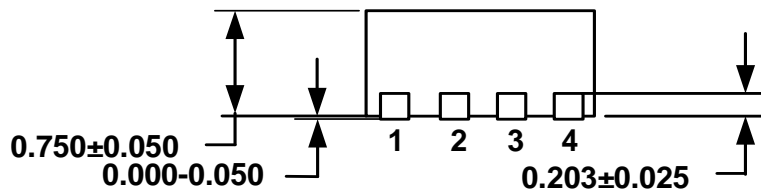
PACKAGE DIAGRAM
MLP 8 2x2mm



TOP VIEW



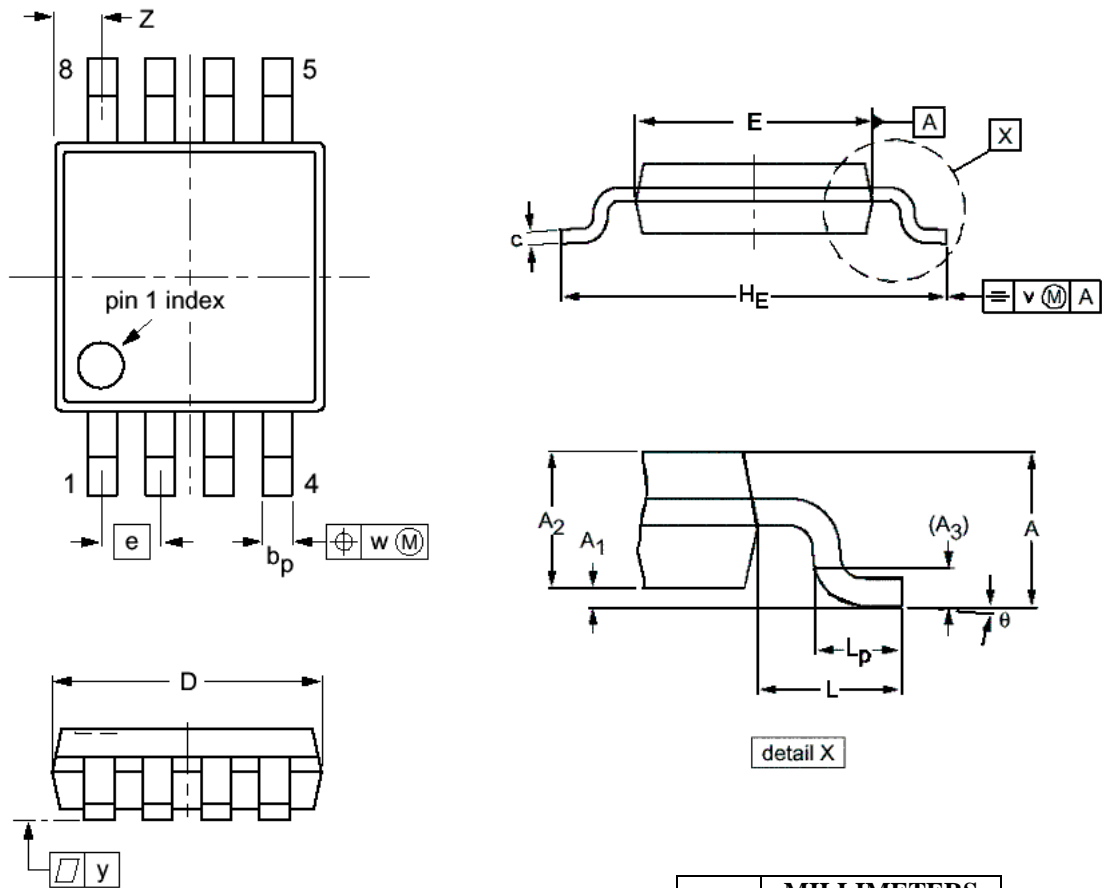
BOTTOM VIEW



SIDE VIEW

Note: All dimensions are in mm

**PACKAGE DIAGRAM
MSOP 8**

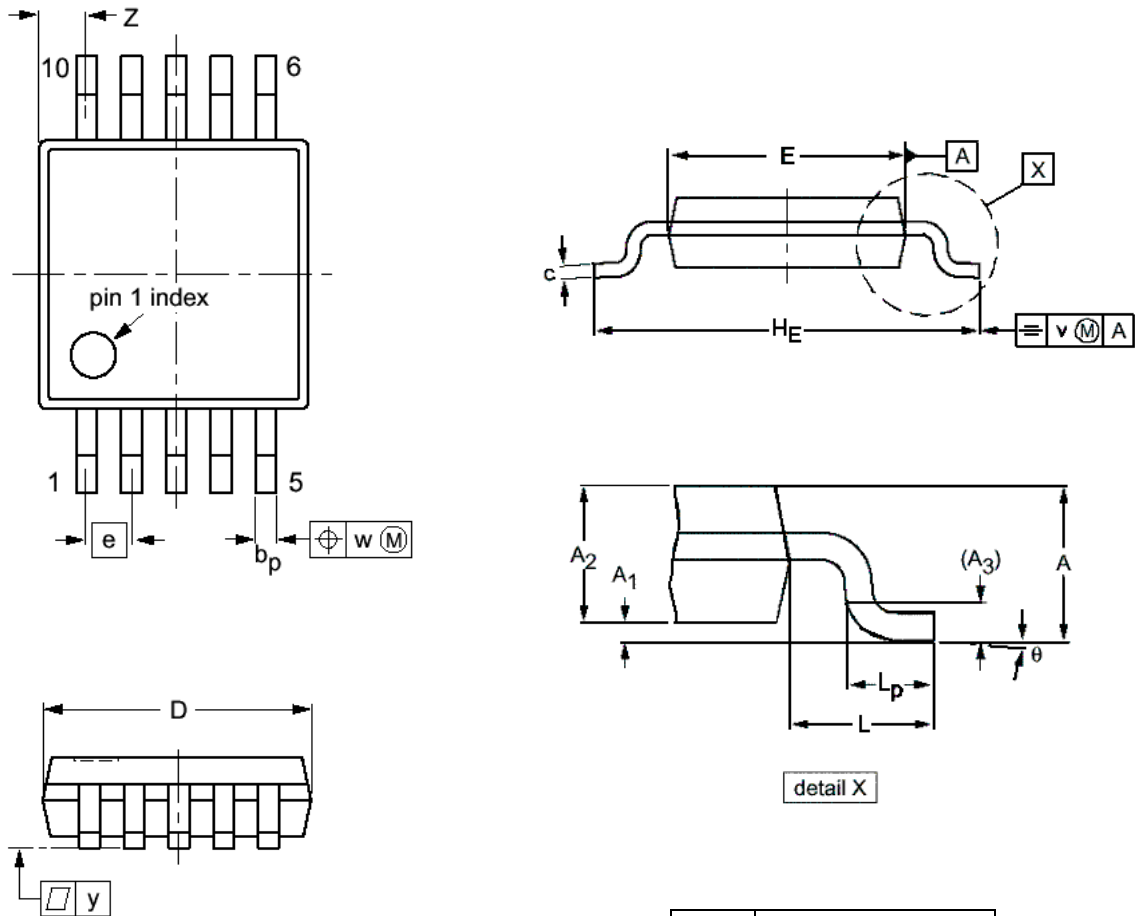


NOTES:

1. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
2. MAXIMUM MOLD PROTRUSION FOR D IS 0.15mm.
3. MAXIMUM MOLD PROTRUSION FOR E IS 0.25mm.

DIM	MILLIMETERS	
	MIN	MAX
A		1.10
A ₁	0.05	0.15
A ₂	0.80	0.95
A ₃	0.25	
b _p	0.25	0.45
c	0.15	0.28
D	2.90	3.10
E	2.90	3.10
e	0.65	
H _E	4.70	5.10
L	0.94	
L _p	0.40	0.70
v	0.10	
w	0.10	
y	0.10	
Z	0.35	0.70
θ	0°	6°

**PACKAGE DIAGRAM
MSOP 10**

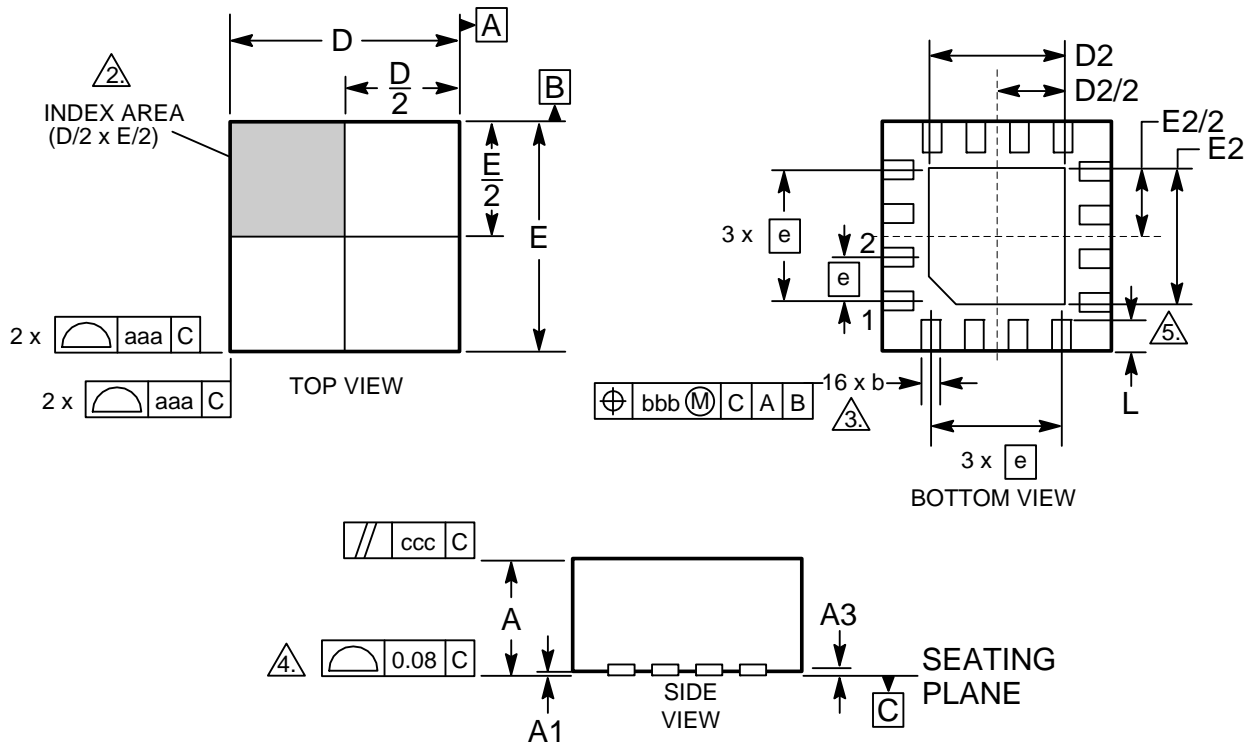


NOTES:

1. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
2. MAXIMUM MOLD PROTRUSION FOR D IS 0.15mm.
3. MAXIMUM MOLD PROTRUSION FOR E IS 0.25mm.

	MILLIMETERS	
	MIN	MAX
A		1.10
A₁	0.05	0.15
A₂	0.80	0.95
A₃	0.25	
b_p	0.15	0.30
c	0.15	0.23
D¹	2.90	3.10
E²	2.90	3.10
e	0.50	
H_E	4.80	5.00
L	0.95	
L_p	0.40	0.70
v	0.10	
w	0.10	
y	0.10	
Z	0.34	0.67
θ	0°	6°

PACKAGE DIAGRAM
MLP 16 3x3mm



NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME T14-1994.
- $\triangle 2$ THE TERMINAL #1 AND PAD NUMBERING CONVENTION SHALL CONFORM TO JESD 95-1 SPP-012.
- $\triangle 3$ DIMENSION b APPLIES TO METALLIZED PAD AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM PAD TIP.
- $\triangle 4$ COPLANARITY APPLIES TO THE EXPOSED PADS AS WELL AS THE TERMINALS.
- $\triangle 5$ INSIDE CORNERS OF METALLIZED PAD MAY BE SQUARE OR ROUNDED

DIM	MILLIMETERS	
	MIN	MAX
A	0.80	1.00
A1	0.00	0.05
A3	0.25 REF	
b	0.18	0.30
D	2.90	3.10
D2	0.25	1.95
E	2.90	3.10
E2	0.25	1.95
e	0.50 BSC	
L	0.30	0.50
aaa	0.25	
bbb	0.10	
ccc	0.10	

AZ10EL16VO
AZ100EL16VO

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